

FORM PTO-1449
(REV.7-80)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO.
859063.491

EXPRESS MAIL NO.
EL773170591US

INFORMATION DISCLOSURE STATEMENT
(Use several sheets if necessary)

APPLICANTS
Walter De Coster et al.

FILING DATE
March 29, 2001

GROUP ART UNIT

1999 U.S. PTO
09/823274
03/29/01

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
AA	3,430,112	02/25/69	Hilbourne	317	235	
AB	4,282,539	08/04/81	Schrader	357	23	
AC	5,132,755	07/21/92	Ueno	357	23.1	
AD	5,357,137	10/18/94	Hayama	257	396	
AE	5,424,571	06/13/95	Liou	257	344	
AF						
AG						
AH						
AI						
AJ						

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION	
				YES	NO
AK	DE2641334A1	03/16/78	Germany (+ English Abstract)		
AL					
AM					
AN					
AO					

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)

AP	Tang et al., "Intrinsic MOSFET Parameter Fluctuations Due to Random Dopant Placement," IEEE, 5(4): pp. 369-376, December, 1997.
AQ	
AR	

EXAMINER

DATE CONSIDERED

* EXAMINER: Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).